



IoT Power efficiency and performance on silicon-proven technology

The rise of IoT and the Cloud and their associated technologies and platforms are slowly but surely fueling the emergence of new market segments that are shaping our way of life. The versatility of the devices combined with the power of networks and data centers to marshal the data for end-spaces is transforming pervasive computing to intelligent computing.

The IoT applications and use-cases that span clients/devices, networks, and data centers drive new requirements for semiconductors including low power, low leakage, smaller and denser packaging, and cost effectiveness. These requirements are at the heart of the "under-the-hood" differentiated technologies and products developed by GLOBALFOUNDRIES that feature low-power, cost-effective performance, RF, embedded memory, analog/power, and packaging.

By forging long-view relationships with customers and partners to design and develop optimized solutions and driving excellence in execution - high yields and time-to-market, we all have a direct role in delivering enhanced experiences and realizing the full potential of the IoT.

- Low power processes > Optimal power consumption
- Wireless IoT Connectivity > Cellular, WiFi, and emerging communication protocols
- Integrated Sensors and Analog > Smart sensors, on-board analog, embedded memory solutions, energy harvesting, short burst battery usage, solar
- IP Support and Security > ARM cores, foundation IP, and complex cores across multiple technologies. Certified foundry, crypto engines, key vaults
- Multi-chip integration and Packaging > In-house packaging solutions complement OSAT partnerships for smaller, thinner, and simpler form factors



40LP, 28SLP, 22FDX (FD-S0I)

GF PRODUCTS 130nm – 55LPx, 22FDX® (FD-S0I)

LOW Sensing & Actuators MID **Collecting & Routing** 8/16-bit ARM Cortex M0+ to M3/M4 16/32-bit ARM Cortex M3/M4 to Cortex A9 Bluetooth® Smart (BLE) / 15.4, Zigbee -BLE /15.4, Zigbee, Wi-Fi - Integrated Cellular LTE typically off-chip Cat 1 / M – External (optional) 50mA-1A, multi-rail Power Management Units

HIGH Application Compute & Vision 32/64-bit ARM Cortex A9+ BLE / 15.4. Wi-Fi. USB: LTE Cat 1/ M /NB-IoT \rightarrow 5G - External

600mA-8A, PMICs, Smart Power

7nm and below

ANALOG-POWER 0-100mA, Standalone Linear Regulators

COMPUTE

CONNECTIVITY

GF Capabilities for IoT

Application Compute & Vision HIGH I Available **MID** Collecting & Routing O In Development External / 3rd Party LOW Sensing & Actuators 55nm LPx 40nm LP Key IoT Requirement 28nm SLP 22FDX® 130nm Compute (MCU class) 8-/16-bit (ARM Cortex M0+ to M3/M4, up to 250MHz) 16-/32-bit (ARM Cortex M3/M4 to Cortex A9, up to 1GHz) 32-/64-bit (ARM Cortex A9+, Above 1GHz+) Memory 0TP MTP eFuse 0 eFlash O eMRAM 0 0 0 0 Stacked die LV-SRAM 0 0 **Battery life** 1-30 days eg. Wearables 1 year eg. Smoke detector, Building sensor 10 years eg. Water & gas meters Connectivity (/w RF integration) BLE / 802.15.4 0 0 0 0 0 0 0 WiFi 802.11 b/g/n 0 GNSS/GPS 0 NFC LTE Cat M / NB-IoT 0 5G / mmWave 0 (5G) Security Authorization (RTL) Crypto (RTL) Secure key gen and vault **Operating Temperature** -20C to +65C (medical) OC to +70C/85C (commercial) -40C to +85C (industrial) -40C to +105C (automotive) -40C to +125C (automotive extended) 0 **Packaging** 2D (FC BGA/ FC CSP) WLP (Fan-in, Fan-out) 2.5D (SiP) Active & Standby Ref: for ARM A7 @800MHz, 22FDX is 50% lower vs 28SLP (Source: Verisilicon); Active power For ARM A9/NEON @150-250MHz, 22FDX is 86-88% lower vs 40LP (Source: GF internal) Standby power Ref: 1pA/cell for 22FDX; actual or relative power savings are application dependent Sensors, Display 0.9V, 1.1V, 0.8V, 1.0V, 0.4V, 0.5V, Supply Voltage (Vdd) 1.2V, 1.5V 0.9V, 1.2V 0.8V 0.65V, 0.8V 1.2V, 9V, 12V 1.1V 1.5V, 2.5V, 1.8V, 2.5V, 1.5V, 1.8V, 1.5V, 1.8V, 1.2V, 1.5V, 1.2V, 1.5V, I/O Voltage 3.3V, 5V, 15V 3.3V, 5V 2.5V, 3.3V 2.5V, 3.3V 1.8V, 2.5V, 3.3V 1.8V 5 @0.9V Multiple Vt's 3@1.2V, 2@0.9V 5 @1.0V, 4 @0.8V 4 4 Superior Analog/RF integration (high fT/fMAX)

IoT-GLOBALFOUNDRIES IP Libraries

Silicon Validated

Design Kit Available

O In Development

Description		130nm	55nm LPx	40nm LP	28nm SLP	22FDX	14nm LPP
Foundation IP Non Volatile Memory	Standard Cells	•	G1 8T/9T/12T	G1//2 9T/12T (G0-Dev)	⊕ 7T/9T/12T	8 T/12T	9T/10.5T (7.5T-Dev)
	Standard Cells-ULP		8T/9T/12T		+ 8T	O 7.5T	
	Standard Cells-ULL		01/31/121		O 7T/9T	O 8T	
	SRAM Compiler: 1P	+	•		•	•	•
	SRAM Compiler: 2P	+	•	+	0		+
	ROM Compiler	+	+	+	+		
	Register File:1P	+	+	•	•		
	Register File: 2P	+	+	+	O	0	
	GPI0	+	+	0	0		•
	ESD			0	0		+
	Electrical Fuse	0	•	0	0		+
	OTP	0		•	+		
	eFlash eMRAM	⊕		0		0	Dlanning
Analog and RF IP	Temp Sensor			•			Planning
	Process Monitor						
	PLL	+	+	•	•		+
	Video DAC	•	_	•			
	Audio ADC / DAC	•			+	•	
Interface IP	DDR		3/2	3 /2	3/2 (4-Dev)	O 4/3	4 /3
	LPDDR		3/2	3 /2	3/2 (4-Dev)	4/3	4 /3
	USB 2.0/3.x	+	+	+	+	•	+
	PCle G1/2/3/4	+	(G1/2)	⊕ (G1/2)	+	•	+
	SATA I/II/III		(I/II)	(1/11)	•		+
	MIPI D-PHY/M-PHY		(D-PHY)	+	•	•	+
	V-By-One PHY				0		
	HDMI/DP		(HDMI)	(HDMI)	•	0	•
	SerDes (max speed)			♣ 6Gbps	⊕ 6Gbps	12.5Gbps	56Gbps
RF IP	BLE / 15.4		0		Planning	0	
	WiFi 802.11		0		Planning	0	
	LTE NB-IoT					Planning	
Power Mgmt IP	LDO, DC-DC, RTC					0	

Contact GF for latest IP availability

GLOBALSOLUTIONS® Design and Manufacturing Ecosystem

GLOBALFOUNDRIES offers comprehensive, state-of-the-art design solutions and services that provide a quick, high-quality and cost-effective path to production for your IoT design.

GLOBALFOUNDRIES' Design Enablement team validates our partners' services and solutions with our silicon process technologies to ensure that they meet the highest standards. Libraries (Standard Cells, Memories)

Analog / Mixed-Signal Processor IP High-speed Interfaces

Full Suite PDK, Reference Flow

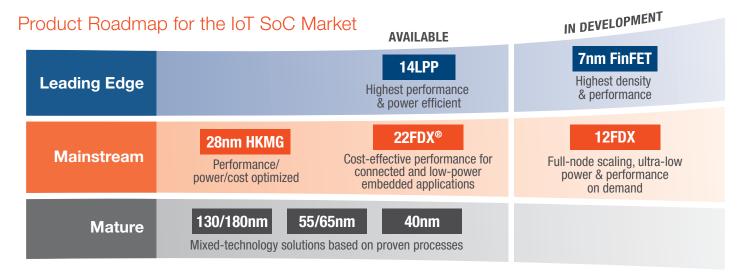
Comprehensive Range of Process Technologies

SoC Packaging

2.5D and 3D Packaging

GF Products – Customer Applications and Solutions





Global Presence for Semiconductor Manufacturing





2600 Great America Way, Santa Clara, CA 95054 USA Tel: +1 408-462-3900 globalfoundries.com/contact-us

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